

DCR3640W34

Phase Control Thyristor

DS6050-3 June 2019 (LN38870)

FEATURES

- Double Side Cooling
- High Surge Capability

APPLICATIONS

- High Power Drives
- High Voltage Power Supplies
- Static Switches

VOLTAGE RATINGS

Part and Ordering Number	Repetitive Peak Voltages V _{DRM} and V _{RRM} V	Conditions
DCR3640W34 DCR3640W32 DCR3640W30 DCR3640W28 DCR3640W26 DCR3640W24	3400 3200 3000 2800 2600 2400	$\begin{split} T_{vj} &= \text{-}40^{\circ}\text{C to 125}^{\circ}\text{C}, \\ I_{DRM} &= I_{RRM} = 400\text{mA}, \\ V_{DRM}, V_{RRM} t_p &= 10\text{ms}, \\ V_{DSM} \& V_{RSM} &= \\ V_{DRM} \& V_{RRM} + 100V \\ respectively \end{split}$

Lower voltage grades available.

ORDERING INFORMATION

When ordering, select the required part number shown in the Voltage Ratings selection table.

For example:

DCR3640W34

Note: Please use the complete part number when ordering and quote this number in any future correspondence relating to your order.

KEY PARAMETERS

V_{DRM}	3400 V
I _{T(AV)}	3640 A
I _{TSM}	54000 A
dV/dt*	1000 V/μs
dI/dt	200 A/μs

* Higher dV/dt selections available

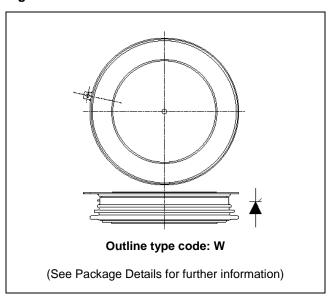


Fig. 1 Package outline



CURRENT RATINGS

$T_{case} = 60$ °C unless stated otherwise

Symbol	Parameter	Test Conditions	Max.	Units
Double Si	de Cooled			
I _{T(AV)}	Mean on-state current	Half wave resistive load	3640	А
I _{T(RMS)}	RMS value	-	5710	А
I _T	Continuous (direct) on-state current	-	5150	А

SURGE RATINGS

Symbol	Parameter	Test Conditions	Max.	Units
I _{TSM}	Surge (non-repetitive) on-state current	10ms half sine, T _{case} = 125°C	54.0	kA
l ² t	I ² t for fusing	$V_R = 0$	14.58	MA ² s

THERMAL AND MECHANICAL RATINGS

Symbol	Parameter	Test Conditions		Min.	Max.	Units
R _{th(j-c)}	Thermal resistance – junction to case	Double side cooled	DC	-	0.007	°C/W
R _{th(c-h)}	Thermal resistance – case to heatsink	Double side cooled	DC	-	0.002	°C/W
T _{vj}	Virtual junction temperature	Blocking V _{DRM} / _{VRRM}		-	125	°C
T _{stg}	Storage temperature range			-40	140	°C
F _m	Clamping force			62	78	kN



DYNAMIC CHARACTERISTICS

Symbol	Parameter	Test Conditions		Min.	Max.	Units
I _{RRM} /I _{DRM}	Peak reverse and off-state current	At V _{RRM} /V _{DRM} , T _{case} = 125°C		-	400	mA
dV/dt	Max. linear rate of rise of off-state voltage	To 67% V _{DRM} , T _j = 125°C, gate open		1000	-	V/µs
dI/dt	Rate of rise of on-state current	From 67% V _{DRM} to 4000A	Repetitive 50Hz	-	200	A/µs
		Gate source 30V, 10Ω,	Non-repetitive	-	1000	A/µs
		$t_r < 0.5 \mu s, T_j = 125 ^{\circ} C$				
V _T	On-state voltage	I _T = 3000A, T _{case} = 125°C			1.41	V
$V_{T(TO)}$	Threshold voltage	T _{case} = 125°C		-	0.95	٧
r _T	On-state slope resistance	T _{case} = 125°C		-	0.153	mΩ
t _{gd}	Delay time	$V_D = 67\% V_{DRM}$, gate source 30V, 10Ω		-	3.0	μs
		$t_r = 0.5 \mu s, T_j = 25^{\circ}C$				
t_q	Turn-off time	$T_j = 125$ °C, $V_R = 100$ V, $dI/dt = 1.5$ A/ μ s,		-	600	μs
		dV _{DR} /dt = 20V/μs linear to 67% V _{DRM}				
Qs	Stored charge	$I_T = 2000A$, tp = 1000us, $T_j = 125$ °C, dl/dt = 1.5A/µs,		-	3500	μC
ΙL	Latching current	$T_j = 25$ °C,		-	1	Α
lμ	Holding current	T _j = 25°C,		-	200	mA

GATE TRIGGER CHARACTERISTICS AND RATINGS

Symbol	Parameter	Test Conditions	Max.	Units
V_{GT}	Gate trigger voltage	V _{DRM} = 5V, T _{case} = 25°C	3	٧
V_{GD}	Gate non-trigger voltage	At 40% V _{DRM} , T _{case} = 125°C	0.3	٧
I _{GT}	Gate trigger current	V _{DRM} = 5V, T _{case} = 25°C	300	mA
I _{GD}	Gate non-trigger current	At 40% V _{DRM} , T _{case} = 125°C	20	mA



CURVES

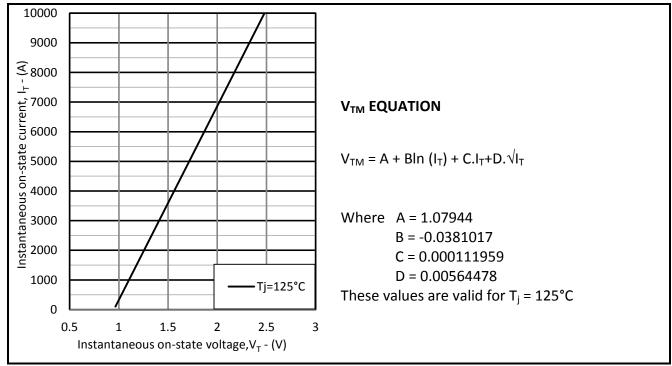


Fig.2 Maximum &minimum on-state characteristics

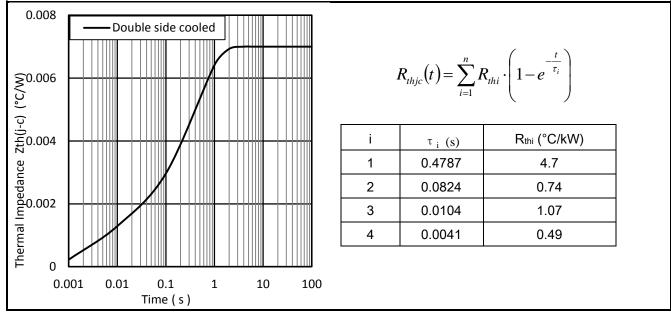
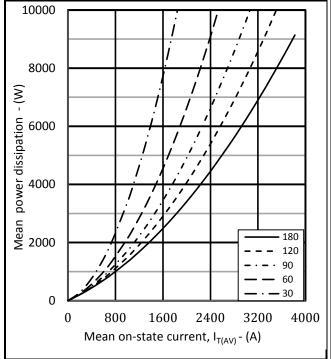
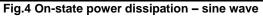


Fig.3 Maximum (limit) transient thermal impedance – junction to case (°C/W)







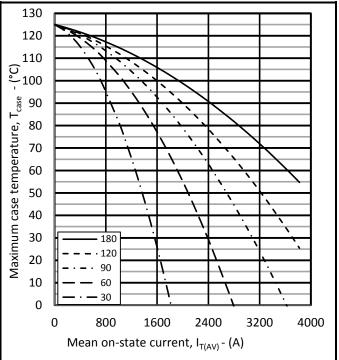


Fig.5 Maximum permissible case temperature, double side cooled – sine wave

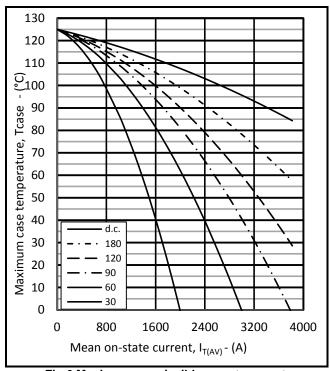


Fig.6 Maximum permissible case temperature, double side cooled – rectangular wave

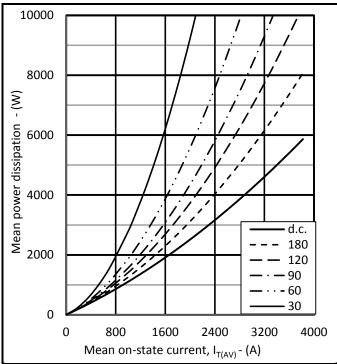
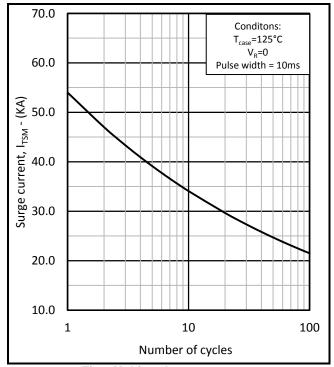


Fig.7 On-state power dissipation - rectangular wave





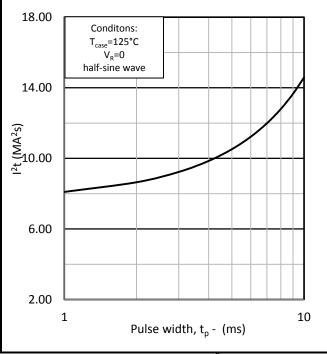


Fig.8 Multi-cycle surge current

Fig.9 Single-cycle I²t

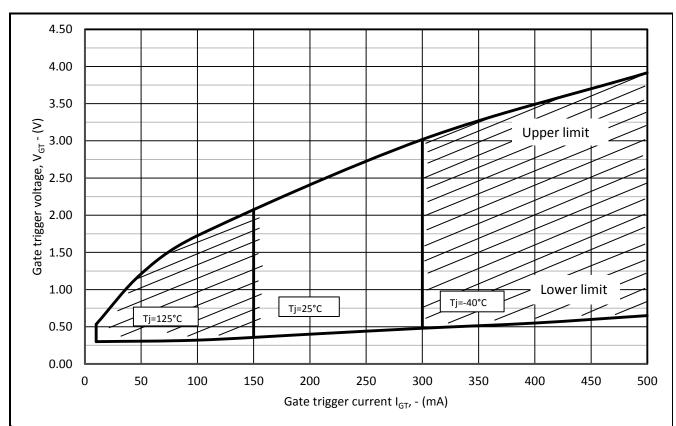


Fig.12 Gate characteristics

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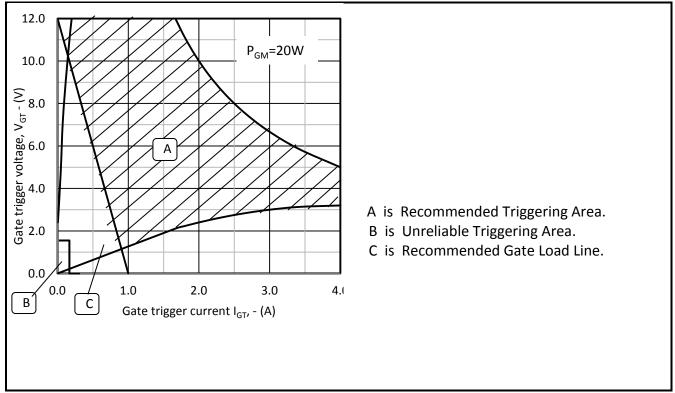


Fig.13 Gate characteristics



PACKAGE DETAILS

For further package information, please contact Customer Services. All dimensions in mm, unless stated otherwise. DO NOT SCALE.

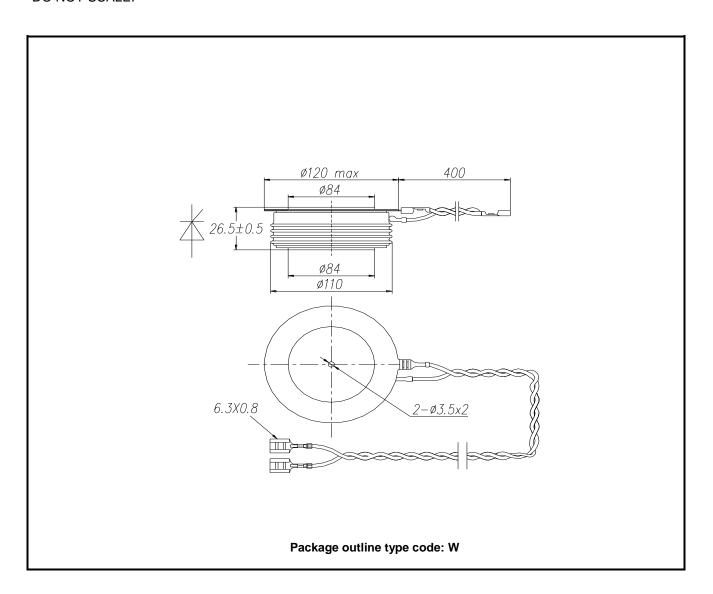


Fig.14 Package outline



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The products must not be touched when operating because there is a danger of electrocution or severe burning. Always use protective safety equipment such as appropriate shields for the product and wear safety glasses. Even when disconnected any electric charge remaining in the product must be discharged and allowed to cool before safe handling using protective gloves.

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Target Information: This is the most tentative form of information and represents a very preliminary specification.

No actual design work on the product has been started.

Preliminary Information:The product design is complete and final characterisation for volume production is in progress. The datasheet represents the product as it is now understood but details may change.

The product has been approved for production and unless otherwise notified by Dynex any product ordered will be supplied to the current version of the data sheet prevailing at the

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